GQ2133

CMOS Positive Voltage Regulator

Description

The GQ2133 series of positive, linear regulators feature low quiescent current (30µA typ.) with low dropout voltage, making them ideal for battery applications.

These rugged devices have both Thermal Shutdown, and Current Fold-back to prevent device failure under the "Worst" of operating conditions.

An additional feature is a "Power Good" detector, which pulls low when the output is out of regulation. The GQ2133 is stable with an output capacitance of 2.2µF or greater.

GTM

Features

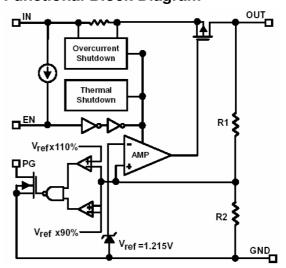
- Very Low Dropout Voltage
- Guaranteed 300mA output
- Over-Temperature Shutdown
- Current Limiting
- Short Circuit Current Fold-back
- Highly Accurate± 1.5%
- Power Good Output Function
- Power-saving Shutdown Mode
- Factor Pre-set Output Voltage

Applications

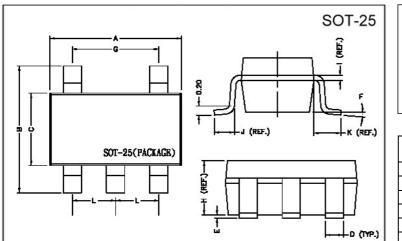
- Battery Powered Widgets
- Instrumentation
- Wireless Devices
- PC Peripherals
- Portable Electronics
- Cordless Phones
- Electronic Scales

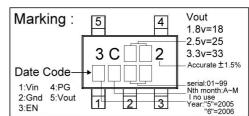
Package Dimensions

Functional Block Diagram



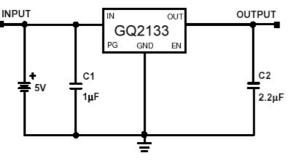
Note: If output voltage specification is lower than 1.215V, Vref will be trimmed to 1.2V





REF.	Millimeter		REF.	Dimensions	
nLI.	Min.	Max.	ΠLΙ.	Millimeter	
Α	2.70	3.10	G	1.90 REF.	
В	2.60	3.00	Н	1.20 REF.	
С	1.40	1.80	-	0.12 REF.	
D	0.30	0.55	J	0.37 REF.	
E	0	0.10	К	0.60 REF.	
F	0°	10°	L	0.95 REF.	

Typical Application Circuit



Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit
Input Max Voltage	Vin	8	V
Output Current	Ιουτ	Pd/(VIN- Vo)	mA
Output Voltage	Vout	1.2~3.8	V
Operating Ambient Temperature	Topr	-40 ~ +85	°C
Junction Temperature	Tj	-40 ~ +125	°C
Maximum Junction Temperature	Tj Max	150	°C
Thermal Resistance	θја	260	°C/W
Power Dissipation(△T=100°C)	PD	380	mW
EDS Classification		В	

Electrical Characteristics Ta=25°C unless otherwise noted

Parameter	Symbol	Condition		Min	ТҮР	Max	Unit
Output Voltage	Vout(E) (Note1)	Vin=Vout(T)+2V, Io=1mA		-1.5%	Vout(T) (Note2)	1.5%	V
Output Current	Io	$V_{IN}=V_{OUT}(T)+2V$, $V_{OUT} \ge V_{OUT}(E)^*0.96$		300	-	-	mA
Current Limit	ILIM	VIN=VOUT(T)+2V, VO>1.2V		300	450	-	mA
Load Regulation	REGLOAD	VIN=VOUT(T)+2V, IO=1mA to 300mA		-1	0.2	1	%
		Io=300mA	$1.2V \leq V_{OUT}(T) \leq 2.0V$	-	-	1300	mV
Dropout Voltage	Vdropout	Vo=Vout(E)-2%	2.0V <vout(t)≦2.8v< td=""><td>-</td><td>-</td><td>400</td></vout(t)≦2.8v<>	-	-	400	
			2.8V <vout(t)< td=""><td>-</td><td>-</td><td>300</td></vout(t)<>	-	-	300	
Quiescent Current	Iq	VIN= VOUT(T)+1V, IO=0mA		-	30	50	μA
Ground Pin Current	Ignd	VIN= VOUT(T)+2V, IO=1mA~300mA		-	35	-	μA
		Io=1mA 1.2V≦Vout(T)≦1.4		-0.2	-	0.2	
Line Regulation	REGLINE		$1.4V < V_{OUT}(T) \le 2.0V$	-0.15	-	0.15	%
		Vout(T)+2	$2.0V < V_{OUT}(T) < 4.0V$	-0.1 -0.4	0.02	0.1 0.4	
Input Voltage	VIN		4.0V≦Vout(T)	-0.4 Note3	0.2	<u> </u>	V
Over Temperature Shutdown	OTS			NOLES	- 150	-	°C
Over Temperature Shudown	OTS			-	30	-	°C
Vo Temperature Coefficient	TC				30	-	ppm/°C
Short Circuit Current(Note4)	Isc	VIN=VOUT(T)+1V, VOUT<0.8V		_	150	300	mA
	150	VIN=VOUT(1)+1V, VOUT<0.8V			60	300	IIIA
Power Supply Rejection	PSRR	Io=100mA	f=1kHz	-	50	-	dB
		Co=2.2µF	f=10kHz	-	20	-	
Output Voltage Noise	eN	f=10Hz~100kHz Io=10mA	Co=2.2Mf	-	30	-	μVrms
EN Input Threshold	VEH	V _{IN} =2.7V to 7V		2.0	-	VIN	V
	Vel	VIN=2.7V to 7V		0	-	0.4	V
EN Input Bias Current	Іен	VEN=VIN, VIN=2.7V to 7V		-	-	0.1	μA
•	IEL	VEN= 0V, VIN=2.7V to 7V		-	-	0.5	μA
,	utdown Supply Current ISD VIN=5V, Vo=0V, VEN <vel< td=""><td>,</td><td>-</td><td>0.5</td><td>1</td><td>μA</td></vel<>		,	-	0.5	1	μA
Shutdown Output Voltage	Vo,sd	Io=0.4mA, Ven $<$ Vel		0	-	0.4	V
Output Under Voltage	νυν	2.5V≦Vout(T)≦5.0V 1.2V≦Vout(T)<2.5V		-	-	85 75	% Vout(T)
	Vov	$1.2V \ge VOU(1) < 2.5V$ $2.5V \le VOUT(T) \le 5.0V$		115	-	-	
Output Over Voltage		1.2V≦Vour(T)<2.5V		125	-	-	% Vout(t)
PG Leakage Current	ILC	VPG=7V		-	-	1.0	μA
<u> </u>		Voin regulation				= 0	V
PG Voltage Rating	Vpg	Voin	regulation	-	-	7.0	v

Note 1: VOUT (E) =Effective Output Voltage (i.e. the output voltage when "VOUT (T) + 2.0V" is provided at the VIN pin while maintaining a certain lout value).

2: VOUT (T) = Specified Output Voltage

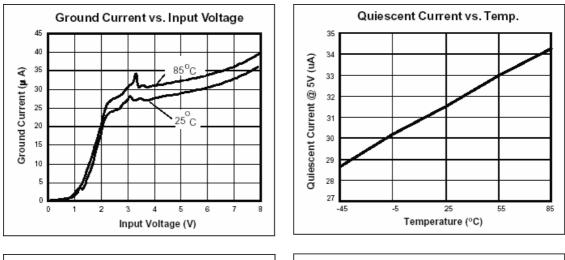
3: VIN (MIN) =VOUT+VDROPOUT

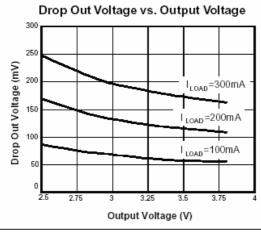
4: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

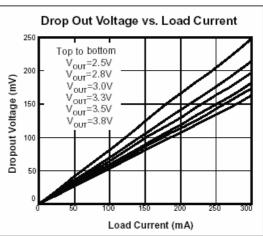
Ordering Information (contd.)

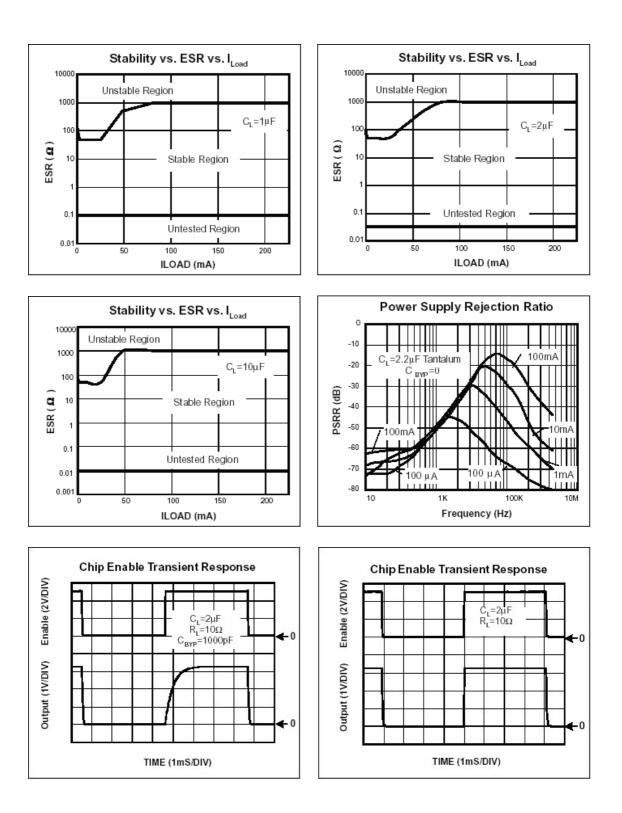
Part Number	Marking	Output Voltage	Part Number	Marking	Output Voltage	
GQ2133-12	3C122 XXXX	1.2V	GQ2133-15	3C152 XXXX	1.5V	
GQ2133-18	3C182 XXXX	1.8V	GQ2133-20	3C202 XXXX	2.0V	
GQ2133-25	3C252 XXXX	2.5V	GQ2133-27	3C272 XXXX	2.7V	
GQ2133-28	3C282 XXXX	2.8V	GQ2133-29	3C292 XXXX	2.9V	
GQ2133-30	3C302 XXXX	3.0V	GQ2133-31	3C312 XXXX	3.1V	
GQ2133-32	3C322 XXXX	3.2V	GQ2133-33	3C332 XXXX		
GQ2133-34	3C342 XXXX	3.4V	GQ2133-35	3C352 XXXX	3.5V	
GQ2133-36	3C362 XXXX	3.6V	GQ2133-37	3C372 XXXX	3.7V	
GQ2133-38	3C382 xxxx	3.8V	GQ2133-2H	3C2H2 XXXX	2.85V	

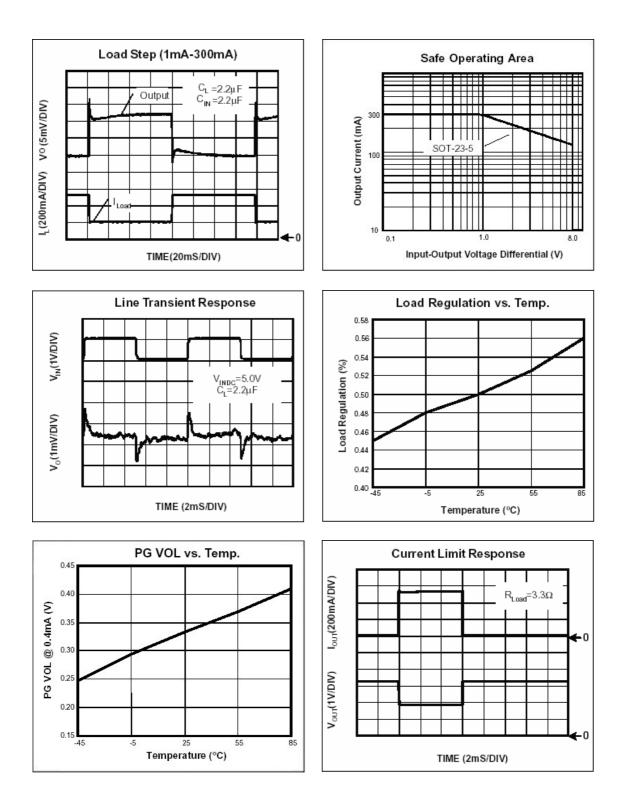
Characteristics Curve

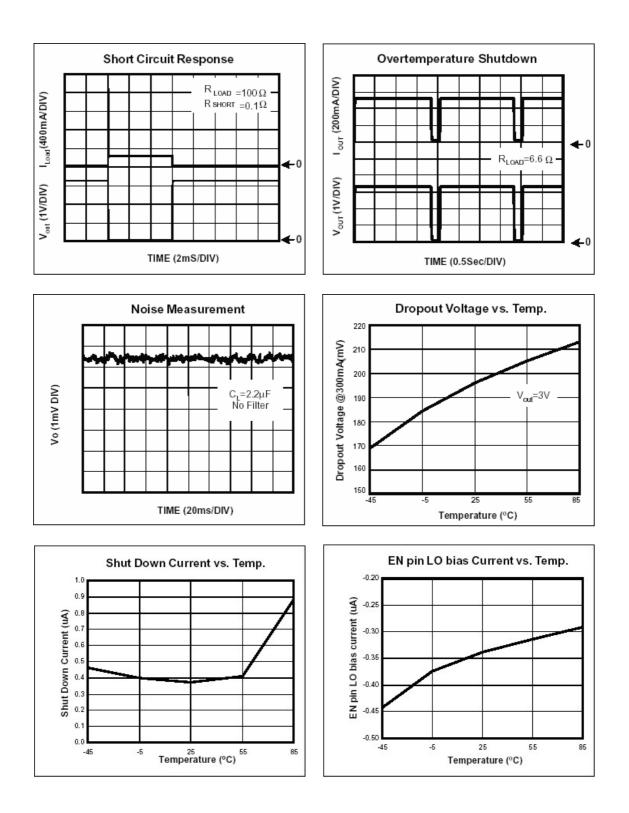












Detailed Description

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The GQ2133 series of COMS regulators contain a PMOS pass transistor, voltage reference, error amplifier, over-current protection, and thermal shutdown, and power good function.

CORPORATION

The P-channel pass transistor receives data from the error amplifier, over-current shutdown, and thermal protection circuits. During normal operation, the error amplifier compares the output voltage to a precision reference. Over-current and Thermal shutdown circuits become active when the junction temperature exceeds 150°C, or the current exceeds 300mA. During thermal shutdown, the output voltage remains low. Normal operation is restored when the junction temperature drops below 120°C.

The GQ2133 switches from voltage mode to current mode when the load exceeds the rated output current. This prevents over-stress. The GQ2133 also incorporates current fold-back to reduce power dissipation when the output is short circuited. This feature becomes active when the output drops below 0.8 volts, and reduces the current flow by 65%. Full current is restored when the voltage exceeds 0.8 volts.

External Capacitors

The GQ2133 is stable with an output capacitance to ground of 2.2µF or greater. Ceramic capacitors have the lowest ESR, and will offer the best AC performance. Conversely, Aluminum Electrolytic capacitors exhibit the highest ESR, resulting in the poorest AC response. Unfortunately, large value ceramic capacitors are comparatively expensive. One option is to parallel a 0.1µF ceramic capacitor with a 10µF Aluminum Electrolytic. The benefit is low ESR, high capacitance, and low overall cost.

A second capacitor is recommended between the input and ground to stabilize Vin. The input capacitor should be at least 0.1µF to have a beneficial effect.

All capacitors should be placed in close proximity to the pins. A "Quiet" ground termination is desirable. This can be achieved with a "Star" connection.

Enable

The Enable pin normally floats high. When actively, pulled low, the PMOS pass transistor shuts off, and all internal circuits are powered down. In this state, the quiescent current is less than 1µA. This pin behaves much like an electronic switch.

Power Good

The GQ2133 includes the Power Good feature. When the output is not within ±15% of the specified voltage, it pulls low. This can occur under the following conditions:

- 1) Input Voltage too low.
- 2) During Over-Temperature.
- 3) During Over-Current.
- 4) If output is pulled up.

(Note: PG pin is an open-drain output.)

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